








	<h2>S3GHE3_AI</h2>
	<p>Hersteller-Teilenummer: S3GHE3_AI</p> <hr/> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <hr/> <p>Teil der Beschreibung: DIODE GEN PURP 400V 3A DO214AB</p> <hr/> <p>Datenblätter:  S3GHE3_AI.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 14000 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S3GHE3_AI
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 400V 3A DO214AB
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	14000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AB, SMC
Supplier Device-Gehäuse	DO-214AB, (SMC)
Diodentyp	Standard
Strom - Richt (Io)	3A
Spannung - Forward (Vf) (Max) @ If	1.15V @ 2.5A
Strom - Sperrleckstrom @ Vr	10µA @ 400V
Spannung - Sperr (Vr) (max)	400V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	2.5µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	60pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

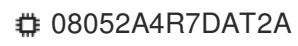

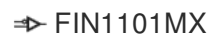



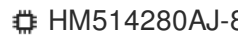
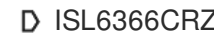


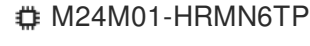
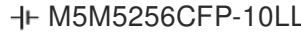
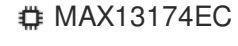
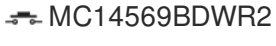

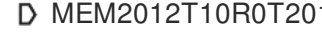
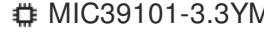
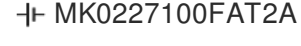
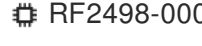

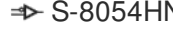



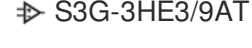
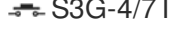
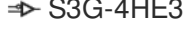
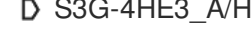

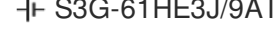
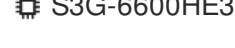
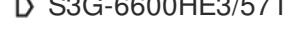

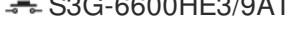
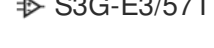
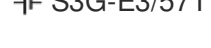




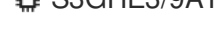
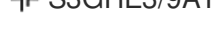


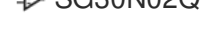

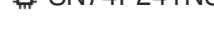

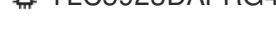

S3GHE3_AI ist neu im Original, Suche S3GHE3_AI Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S3GHE3_AI Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S3GHE3_AI: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S3GHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 3A DO214AB</p>	 <p>S3GTR Sensitron Semiconductor / SMC Diode Solutions DIODE GEN PURP 400V 3A SMC</p>	 <p>S3GHE3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 3A DO214AB</p>	 <p>S3GHE3/57T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 3A DO214AB</p>
 <p>S3GHE3/9AT Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 3A DO214AB</p>	 <p>S3GHM3/57T Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 3A DO214AB</p>	 <p>S3GHR7G TSC (Taiwan Semiconductor) DIODE GEN PURP 400V 3A DO214AB</p>	 <p>S3GHE3_AI Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 3A DO214AB</p>

heiße Teile

Mehr

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